

SANYO	No.2209C	2SB1223/2SD1825
	PNP/NPN Epitaxial Planar Silicon Darlington Transistor	
Driver Applications		

Applications

- Suitable for use in control of motor drivers, printer hammer drivers, relay drivers, and constant-voltage regulators.

Features

- High DC current gain.
- Large current capacity and wide ASO.
- Micaless package facilitating mounting.

() : 2SB1223

Absolute Maximum Ratings at Ta = 25°C

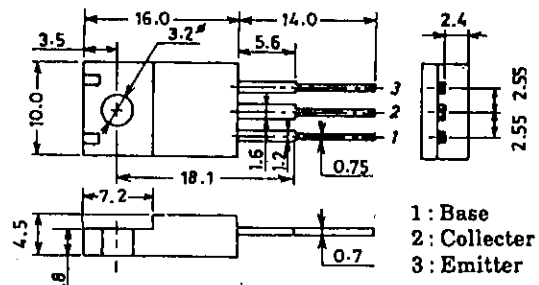
Collector-to-Base Voltage	V _{CB0}	(-)70	V	unit
Collector-to-Emitter Voltage	V _{CEO}	(-)60	V	
Emitter-to-Base Voltage	V _{EBO}	(-)6	V	
Collector Current	I _C	(-)4	A	
Collector Current (Pulse)	I _{CP}	(-)6	A	
Collector Dissipation	P _C	2.0	W	
		20	W	
Junction Temperature	T _j	150	°C	
Storage Temperature	T _{stg}	-55 to +150	°C	

T_c = 25°C

Electrical Characteristics at Ta = 25°C

			min	typ	max	unit
Collector Cutoff Current	I _{CBO}	V _{CB} = (-)40V, I _E = 0			(-)0.1	mA
Emitter Cutoff Current	I _{EBO}	V _{EB} = (-)5V, I _C = 0			(-)3.0	mA
DC Current Gain	h _{FE}	V _{CE} = (-)2V, I _C = (-)2A	2000	5000		
Gain-Bandwidth Product	f _T	V _{CE} = (-)5V, I _C = (-)2A		20		MHz
C-E Saturation Voltage	V _{CE(sat)}	I _C = (-)2A, I _B = (-)4mA		0.9	(-)1.5	V
				(-1.0)		V
B-E Saturation Voltage	V _{BE(sat)}	I _C = (-)2A, I _B = (-)4mA			(-)2.0	V
C-B Breakdown Voltage	V _{(BR)CBO}	I _C = (-)5mA, I _E = 0	(-)70			V
C-E Breakdown Voltage	V _{(BR)CEO}	I _C = (-)50mA, R _{BE} = ∞	(-)60			V
Turn-ON Time	t _{on}	See specified Test Circuit.		0.6		μs
		"		(0.5)		μs
Storage Time	t _{stg}	"		2.7		μs
		"		(1.4)		μs
Fall Time	t _f	"		1.6		μs
		"		(1.2)		μs

Package Dimensions 2041A
(unit : mm)

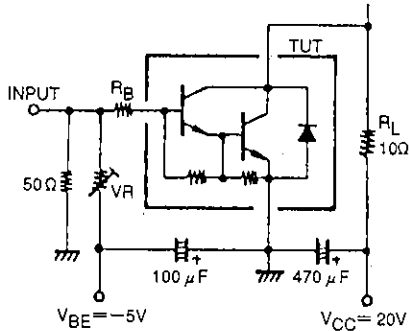


SANYO : TO220ML

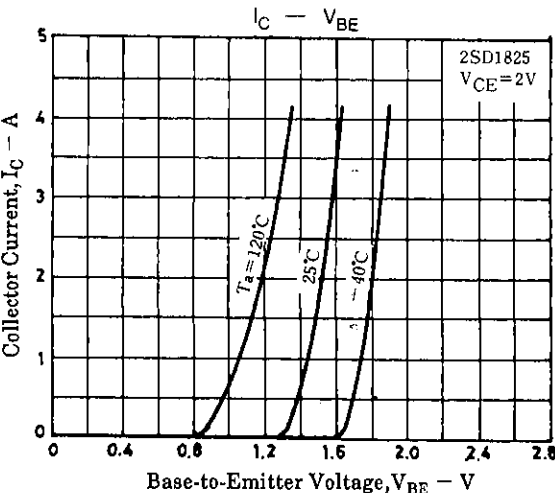
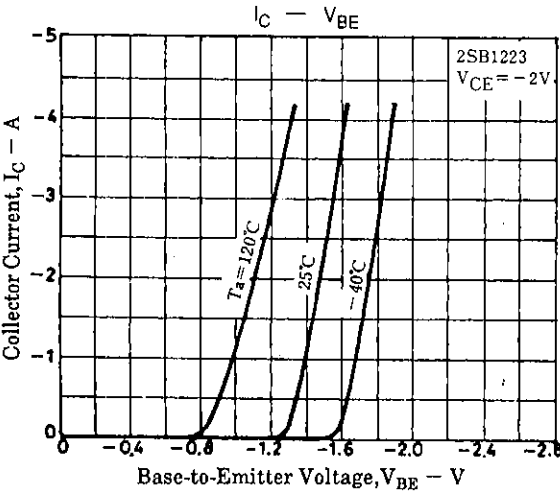
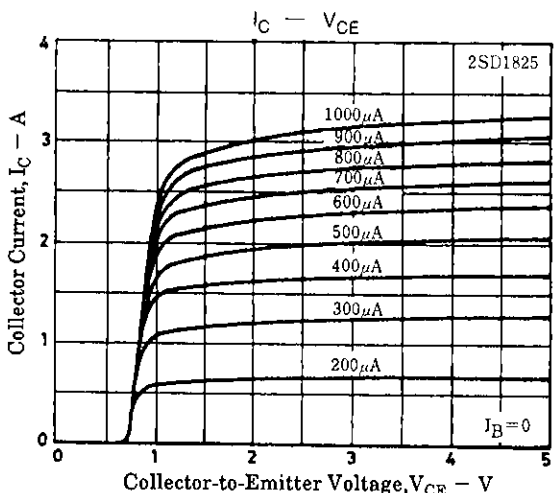
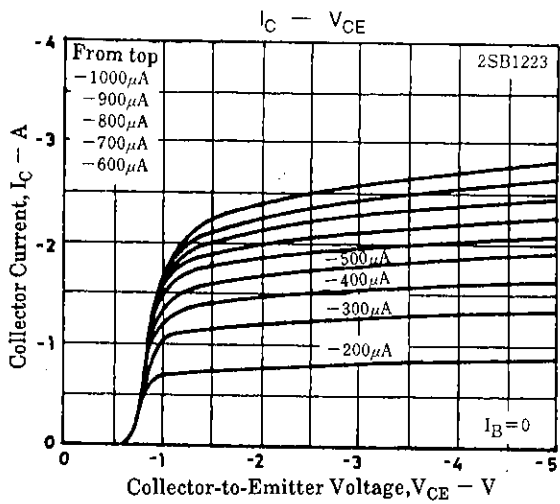
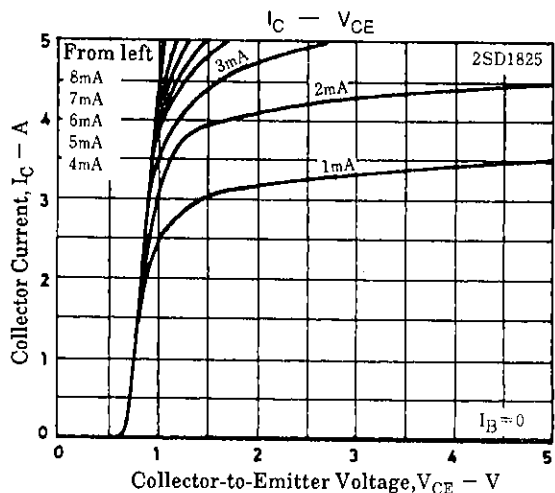
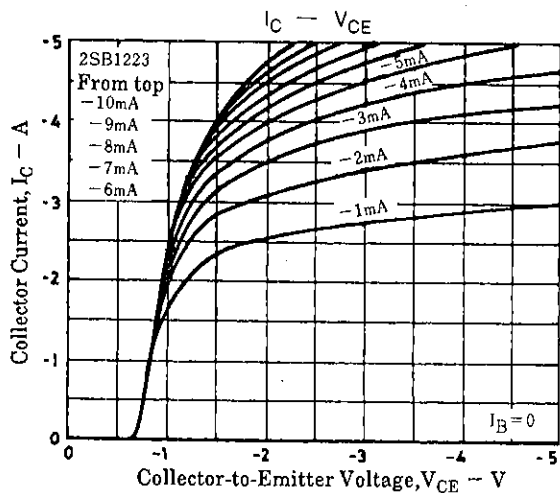
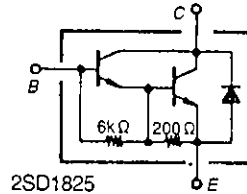
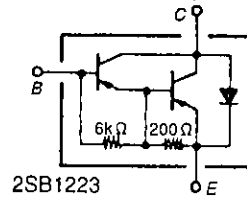
SANYO Electric Co., Ltd. Semiconductor Business Headquarters
TOKYO OFFICE Tokyo Bldg. 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

Specified Test Circuit (For PNP, the polarity is reversed.)

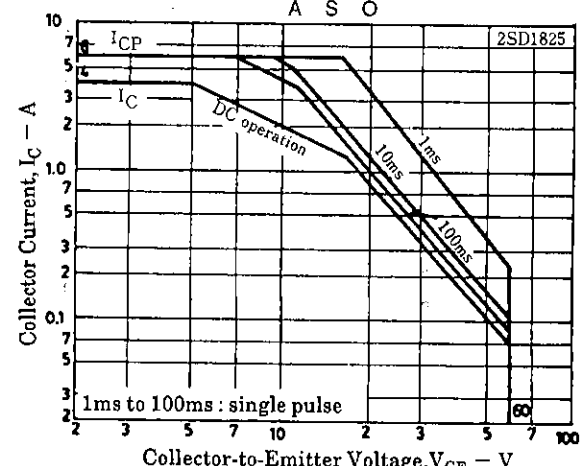
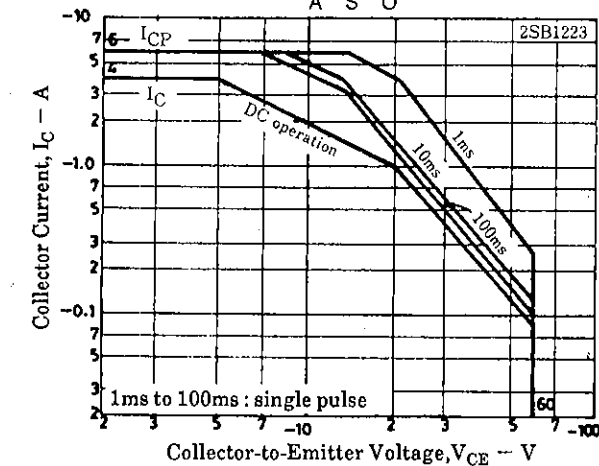
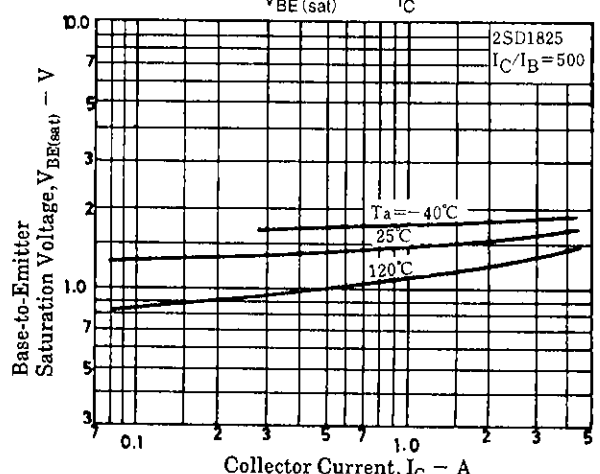
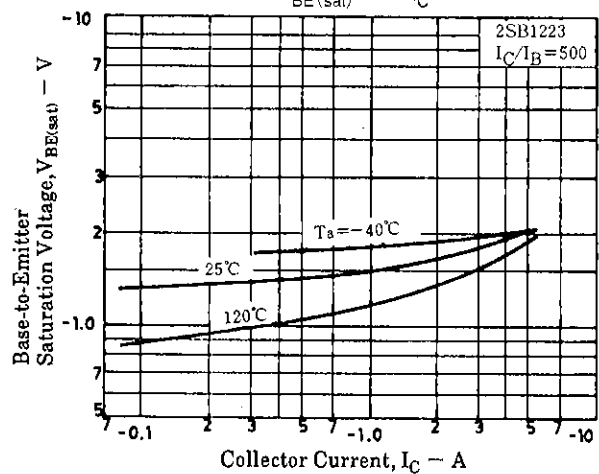
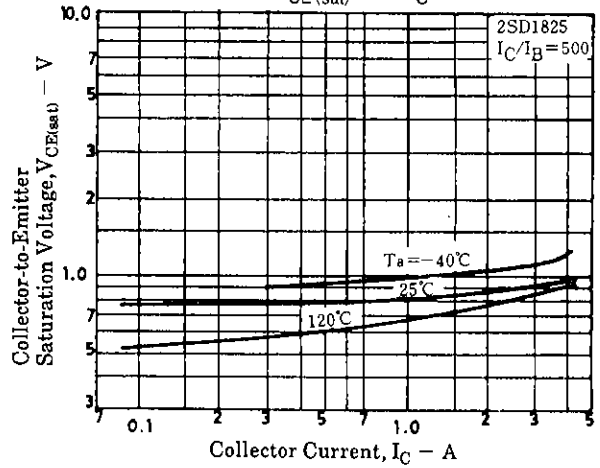
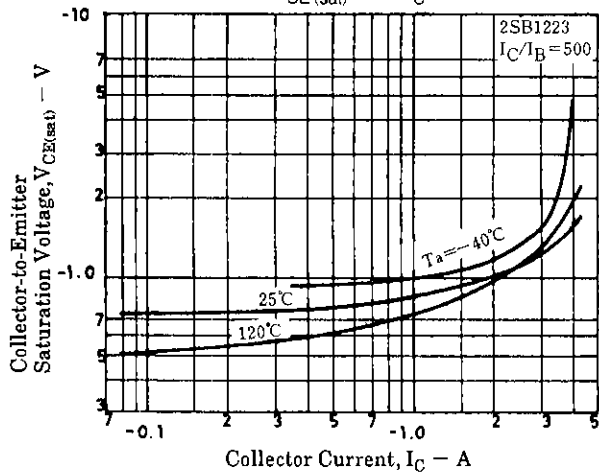
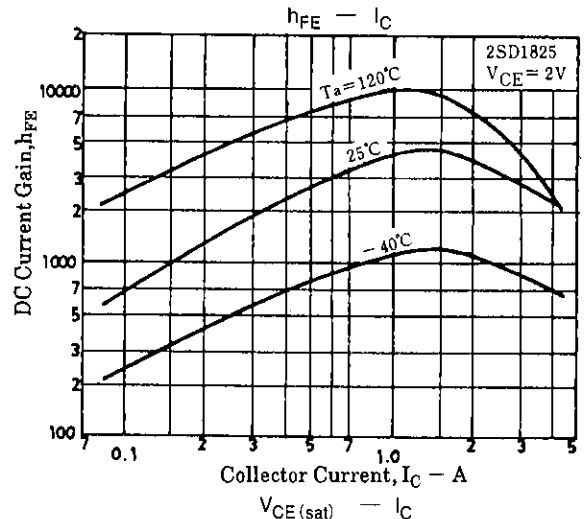
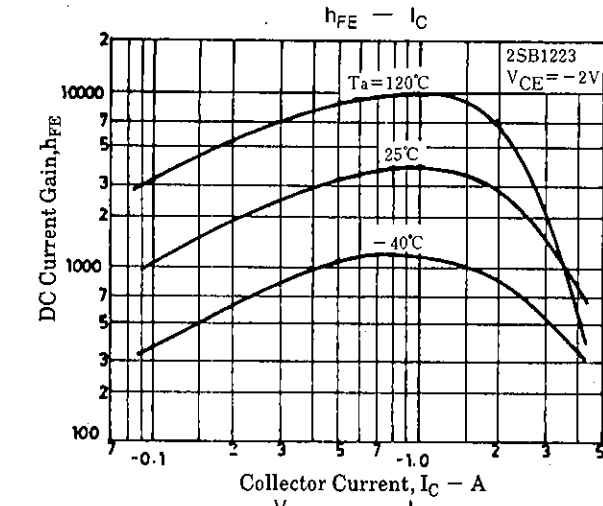
PW = 50μs, Duty cycle ≤ 1%
 500I_{B1} = -500I_{B2} = I_C = 2A



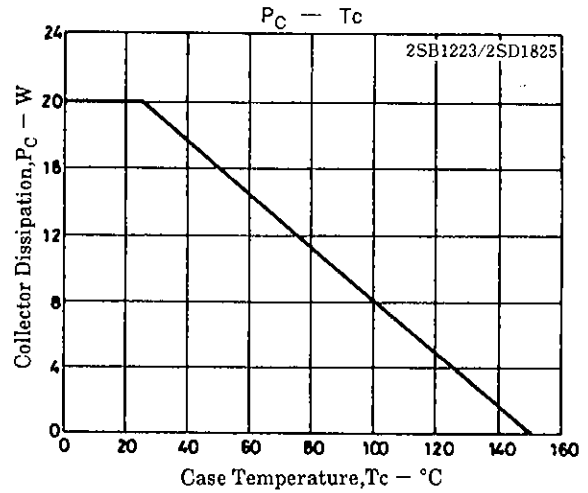
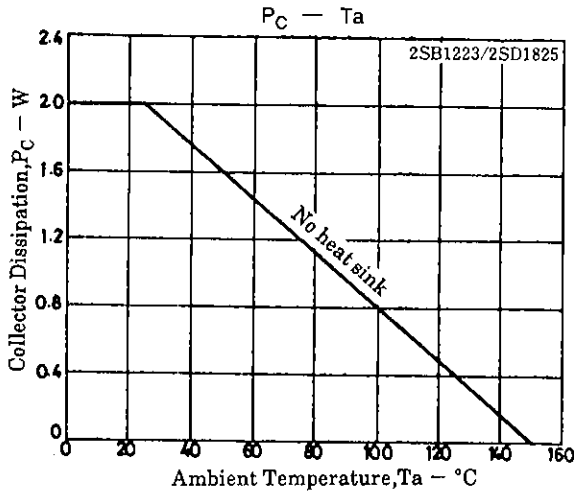
Electrical Connection



2SB1223/2SD1825



2SB1223/2SD1825



■ No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.

■ Anyone purchasing any products described or contained herein for an above-mentioned use shall:

- ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use:
- ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.

■ Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of August, 1996. Specifications and information herein are subject to change without notice.